

Micronas.5903  
09/780,796

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

<b>APPLICANT:</b>	Czech et al.	<b>GROUP:</b>	2811
<b>SERIAL NO:</b>	09/780,976	<b>EXAMINER:</b>	Steven Loke
<b>FILED:</b>	February 9, 2001		
<b>FOR:</b>	LATERAL THYRISTOR STRUCTURE FOR PROTECTION AGAINST ELECTROSTATIC DISCHARGE		

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

## AMENDMENT

This amendment is in response to the Official Action dated December 4, 2003.

Please amend the application as follows:

IN THE CLAIMS:

Cancel claim 6.

Amend claims 8, 9 and 12 as follows:

1. (Previously Amended) A lateral thyristor structure for protection against electrostatic discharge, comprising:

at least two lateral thyristors, which each include

a semiconductor substrate of a first conduction type, with a surface;

a well region of a second conduction type, opposite to said first conduction

type, which is introduced into said surface of said semiconductor substrate;

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